TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC05AP,TC74HC05AF

Hex Inverter (open drain)

The TC74HC05A is a high speed CMOS INVERTER fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

Pin configuration and function are the same as the TC74HC04A, but the TC74HC05A has high performance MOS N-channel transistor (open-drain) outputs.

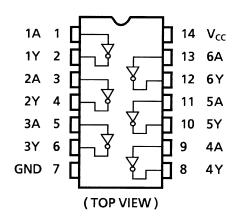
This device can, therefore, with a suitable pull-up resistors, be used in wired-AND, LED drive and other applications.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

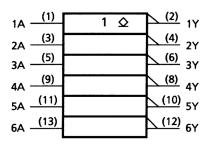
Features

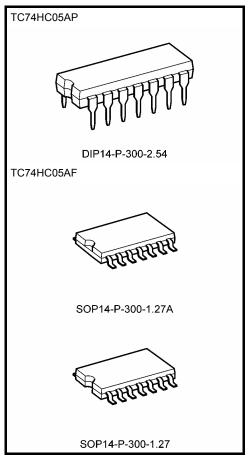
- High speed: $t_{pz} = 8 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 1 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Output drive capability: 10 LSTTL loads
- Wide operating voltage range: VCC (opr) = 2~6 V
- Open drain structure.
- Pin and function compatible with 74LS05

Pin Assignment



IEC Logic Symbol





Weight

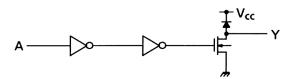
DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.) SOP14-P-300-1.27 : 0.18 g (typ.)

Truth Table

Α	Υ
L	Z
Н	L

Z: High impedance

System Diagram (per gate)



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	+25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	−65 ~ 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of $Ta = -40 \sim 65$ °C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2~6	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
		0~1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0~500 (V _{CC} = 4.5 V)	ns
		0~400 (V _{CC} = 6.0 V)	

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics Symbol Test Condition			Ta = 25°C			Ta = -40~85°C				
				V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
		_		2.0	1.50	_	_	1.50	_	
High-level input voltage	V_{IH}			4.5	3.15	_	_	3.15	_	V
					4.20	_	_	4.20	_	
				2.0	_	_	0.50	_	0.50	
Low-level input voltage	V_{IL}	_		4.5	_	_	1.35	_	1.35	V
				6.0	_	_	1.80	_	1.80	
	VoL	V _{IN} = V _{IH}	Ι _{ΟL} = 20 μΑ	2.0	_	0.0	0.1	_	0.1	
				4.5	_	0.0	0.1	_	0.1	
Low-level output voltage				6.0	_	0.0	0.1	_	0.1	V
			I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33	
			$I_{OL} = 5.2 \text{ mA}$	6.0	_	0.18	0.26	_	0.33	
Output off-state	la-	$V_{IN} = V_{II}$	d or VIL	6.0	0.0		±0.5		±5.0	^
current	loz	$V_{OUT} = V_{CC}$		0.0	,	_	±0.5	_	±3.0	μΑ
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	_	_	±0.1	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		6.0	_	_	1.0	_	10.0	μА

AC Characteristics (CL = 15 pF, V_{CC} = 5 V, Ta = 25°C, input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t _{THL}	_	_	4	8	ns
Propagation delay time	t _{pLZ}	$R_L = 1 \text{ k}\Omega$	_	8	15	ns
Propagation delay time	t _{pZL}	$R_L = 1 \text{ k}\Omega$	_	6	15	ns



AC Characteristics (C $_L = 50\ \text{pF},\ \text{input:}\ t_r = t_f = 6\ \text{ns})$

		Symbol Test Condition VCC (V)		Ta = 25°C			Ta = -40~85°C		
Characteristics Sym	Symbol			Min	Тур.	Max	Min	Max	Unit
			2.0	_	30	75	_	95	
Output transition time	t _{THL}	_	4.5	_	8	15	_	19	ns
			6.0	_	7	13	_	16	
			2.0	_	20	90	_	115	
Propagation delay time	t_{pLZ}	$R_L = 1 \text{ k}\Omega$	4.5	_	11	18	_	23	ns
			6.0	_	10	15	_	20	
Propagation delay time			2.0	_	33	90	_	115	
	t_{pZL}	$R_L = 1 k\Omega$	4.5	_	9	18	_	23	ns
			6.0	_	7	15	_	20	
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Output capacitance	C _{OUT}	_		_	3	_	_	_	pF
Power dissipation capacitance	C _{PD}				7				nE.
	(Note)	_			/				pF

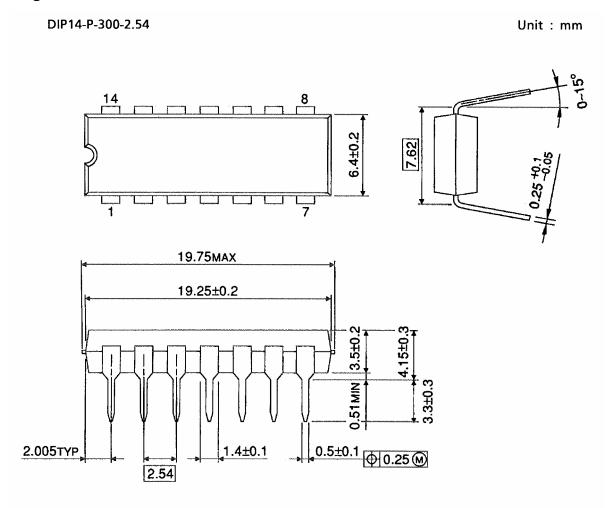
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6$ (per gate)

Package Dimensions

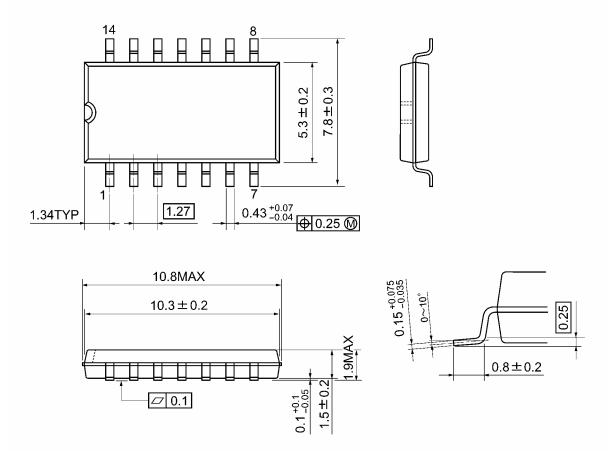


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Weight: 0.96 g (typ.)

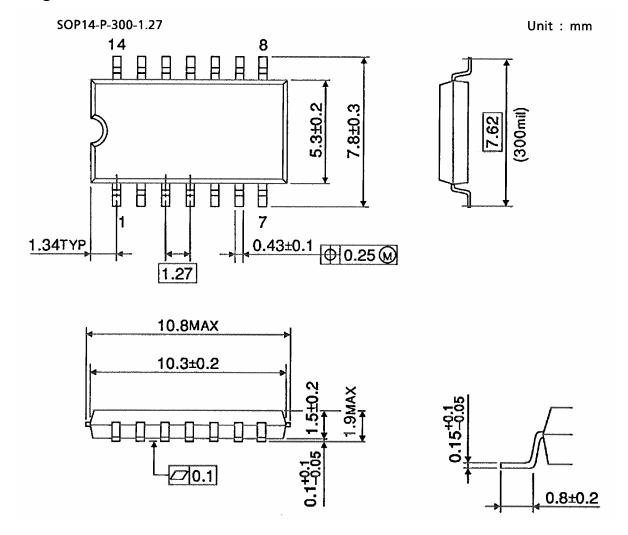
Package Dimensions

SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions



Weight: 0.18 g (typ.)

Note: Lead (Pb)-Free Packages

DIP14-P-300-2.54 SOP14-P-300-1.27A

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